

MPS6560 MPS6561 NPN
MPS6562 MPS6563 PNP

**COMPLEMENTARY
SILICON TRANSISTORS**



TO-92 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR MPS6560 series devices are complementary silicon transistors manufactured by the epitaxial planar process and designed for general purpose amplifier and switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	MPS6560 MPS6562	MPS6561 MPS6563	UNITS
Collector-Base Voltage	V_{CBO}	25	20	V
Collector-Emitter Voltage	V_{CEO}	25	20	V
Emitter-Base Voltage	V_{EBO}		5.0	V
Continuous Collector Current	I_C		600	mA
Power Dissipation	P_D		625	mW
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D		1.5	W
Operating and Storage Junction Temperature	T_J, T_{stg}		-65 to +150	$^\circ\text{C}$
Thermal Resistance	θ_{JA}		200	$^\circ\text{C/W}$
Thermal Resistance	θ_{JC}		83.3	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$)

SYMBOL	TEST CONDITIONS	MPS6560 MPS6562		MPS6561 MPS6563		UNITS
		MIN	MAX	MIN	MAX	
I_{CBO}	$V_{CB}=20\text{V}$	-	100	-	100	nA
I_{CEO}	$V_{CE}=\text{Rated } V_{CEO}$	-	100	-	100	nA
I_{EBO}	$V_{EB}=4.0\text{V}$	-	100	-	100	nA
BV_{CBO}	$I_C=100\mu\text{A}$	25	-	20	-	V
BV_{CEO}	$I_C=10\text{mA}$	25	-	20	-	V
BV_{EBO}	$I_E=100\mu\text{A}$	5.0	-	5.0	-	V
$V_{CE(SAT)}$	$I_C=350\text{mA}, I_B=35\text{mA}$	-	-	-	0.5	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$	-	0.5	-	-	V
$V_{BE(ON)}$	$V_{CE}=1.0\text{V}, I_C=350\text{mA}$	-	-	-	1.2	V
$V_{BE(ON)}$	$V_{CE}=1.0\text{V}, I_C=500\text{mA}$	-	1.2	-	-	V
h_{FE}	$V_{CE}=1.0\text{V}, I_C=10\text{mA}$	35	-	35	-	
h_{FE}	$V_{CE}=1.0\text{V}, I_C=100\text{mA}$	50	-	50	-	
h_{FE}	$V_{CE}=1.0\text{V}, I_C=350\text{mA}$	-	-	50	200	
h_{FE}	$V_{CE}=1.0\text{V}, I_C=500\text{mA}$	50	200	-	-	
f_T	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=30\text{MHz}$	60	-	60	-	MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$	-	30	-	30	pF

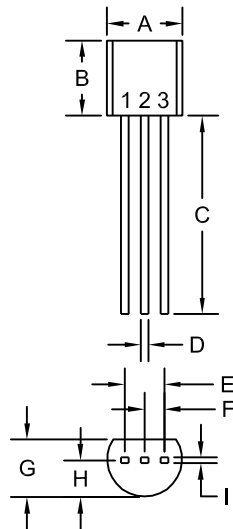
R1 (8-November 2013)

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TO-92 CASE - MECHANICAL OUTLINE



R1

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:

FULL PART NUMBER

R1 (8-November 2013)